6 GHz to 26 GHz, GaAs MMIC Fundamental Mixer

Data Sheet

HMC773ALC3B

FEATURES

- Conversion loss: 9 dB typical
- Local oscillator (LO) to radio frequency (RF) isolation: 37 dB typical
- LO to intermediate frequency (IF) isolation: 37 dB typical
- RF to IF isolation: 20 dB typical
- Input third-order intercept (IP3): 20 dBm typical
- Input second-order intercept (IP2): 50 dBm typical
- Input power for 1 dB compression (P1dB): 10 dBm typical
- IF bandwidth: dc to 8 GHz
- Passive: no dc bias required
- 3 mm × 3 mm, 12-terminal ceramic LCC package

APPLICATIONS

- Point to point radios
- Point to multipoint radios and very small aperture terminals (VSATs)
- Test equipment and sensors
- Military end use

FUNCTIONAL BLOCK DIAGRAM

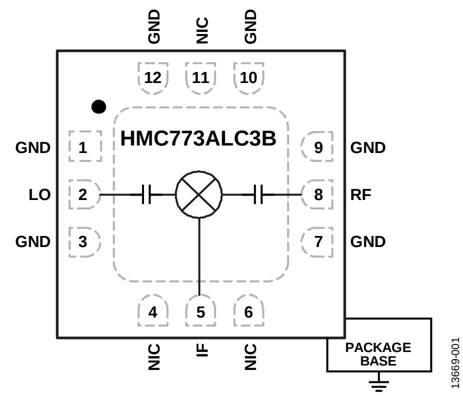

Figure 1.

GENERAL DESCRIPTION

The HMC773ALC3B is a general-purpose, double balanced mixer in a leadless, RoHS compliant LCC package that can be used as an upconverter or downconverter from 6 GHz to 26 GHz. This mixer requires no external components or matching circuitry.

The HMC773ALC3B provides excellent LO to RF and LO to IF suppression due to optimized balun structures. The mixer operates well with LO drive levels of 13 dBm or above. The HMC773ALC3B eliminates the need for wire bonding, allowing use of surface-mount manufacturing techniques.

Rev. F
Document Feedback

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9/2015—v.00.0715 to Rev. A

This Hittite Microwave Products data sheet has been reformatted to meet the styles and standards of Analog Devices, Inc.

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SPECIFICATIONS

ELECTRICAL SPECIFICATIONS

T_A = 25°C, IF = 500 MHz, LO drive = 13 dBm, RF frequency range = 6.0 GHz to 16.0 GHz, all measurements performed as a downconverter with the upper sideband selected, unless otherwise noted.

Table 1.

Parameter	Symbol	Min	Typ	Max	Unit
FREQUENCY RANGE					
Radio Frequency	RF	6		16	GHz
Local Oscillator	LO	6		16	GHz
Intermediate Frequency	IF	dc		8	GHz
CONVERSION LOSS			9	12	dB
NOISE FIGURE			10		dB
ISOLATION					
LO to RF		33	37		dB
LO to IF		30	37		dB
RF to IF		11	15		dB
INPUT THIRD-ORDER INTERCEPT	IP3	11	17		dBm
INPUT SECOND-ORDER INTERCEPT	IP2		45		dBm
INPUT POWER					
1 dB Compression	P1dB		10		dBm
RETURN LOSS					
RF Port			12		dB
LO Port			12		dB

T_A = 25°C, IF = 500 MHz, LO drive = 13 dBm, RF frequency range = 16.0 GHz to 26.0 GHz, all measurements performed as a downconverter with the upper sideband selected, unless otherwise noted.

Table 2.

Parameter	Symbol	Min	Typ	Max	Unit
FREQUENCY RANGE					
Radio Frequency	RF	16		26	GHz
Local Oscillator	LO	16		26	GHz
Intermediate Frequency	IF	dc		8	GHz
CONVERSION LOSS			9	14	dB
NOISE FIGURE			12		dB
ISOLATION					
LO to RF		33	37		dB
LO to IF		32	37		dB
RF to IF		15	20		dB
INPUT THIRD-ORDER INTERCEPT	IP3	16	20		dBm
INPUT SECOND-ORDER INTERCEPT	IP2		50		dBm
INPUT POWER					
1 dB Compression	P1dB		10		dBm
RETURN LOSS					
RF Port			10		dB
LO Port			12		dB

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
RF Input Power	21 dBm
LO Input Power	21 dBm
IF Input Power	21 dBm
IF Source and Sink Current	2 mA
Channel Temperature	175°C
Continuous P_{DISS} (T = 85°C) (Derate 4.44 mw/°C Above 85°C)	400 mW
Maximum Peak Reflow Temperature (MSL3)[1]	260°C
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	−40°C to +85°C
Electrostatic Discharge (ESD) Sensitivity	
Human Body Model (HBM)	2000 V (Class 2)
Field Induced Charged Device Model (FICDM)	1200 V (Class C5)

[1] See the Ordering Guide section.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

θ_{JA} is the natural convection junction to ambient thermal resistance measured in a one cubic foot sealed enclosure.

θ_{JC} is the junction to case thermal resistance.

Table 4. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
E-12-4[1]	120	225	°C/W

[1] See JEDEC standard JESD51-2 for additional information on optimizing the thermal impedance (PCB with 3 × 3 vias).

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

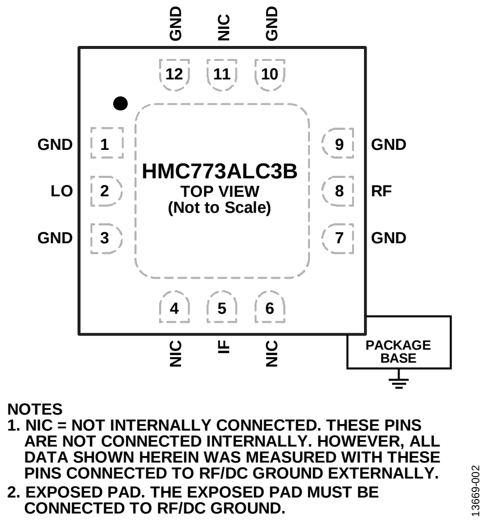


Figure 2. Pin Configuration

Table 5. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 3, 7, 9, 10, 12	GND	Ground. Connect these pins and package bottom to RF/dc ground. See Figure 3 for the GND interface schematic.
2	LO	Local Oscillator Port. This pin is ac-coupled and matched to 50 Ω. See Figure 4 for the LO interface schematic.
4, 6, 11	NIC	Not Internally Connected. These pins are not connected internally. However, all data shown herein was measured with these pins connected to RF/dc ground externally.
5	IF	Intermediate Frequency Port. This pin is dc-coupled. For applications not requiring operation to dc, block this pin externally using a series capacitor with a value that passes the necessary IF frequency range. For operation to dc, to prevent device malfunction or failure, this pin must not source or sink more than 2 mA of current. See Figure 5 for the IF interface schematic.
8	RF	Radio Frequency Port. This pin is ac-coupled and matched to 50 Ω. See Figure 6 for the RF interface schematic.
	EP	Exposed Pad. The exposed pad must be connected to RF/dc ground.

INTERFACE SCHEMATICS

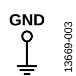


Figure 3. GND Interface

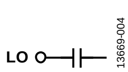


Figure 4. LO Interface

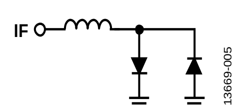


Figure 5. IF Interface

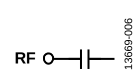


Figure 6. RF Interface

TYPICAL PERFORMANCE CHARACTERISTICS

DOWNCONVERTER, UPPER SIDEBAND, IF = 500 MHz

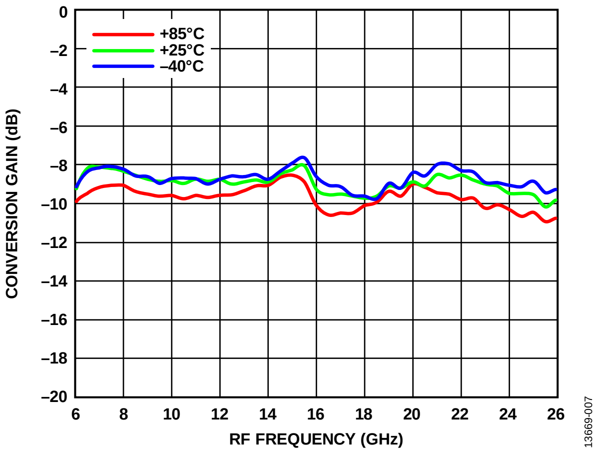


Figure 7. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

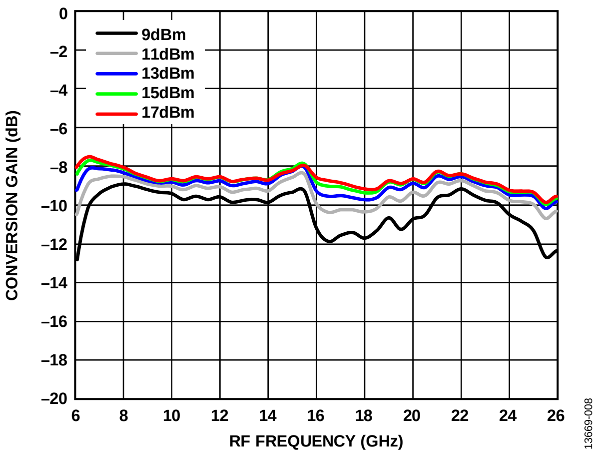


Figure 8. Conversion Gain vs. RF Frequency at Various LO Drives

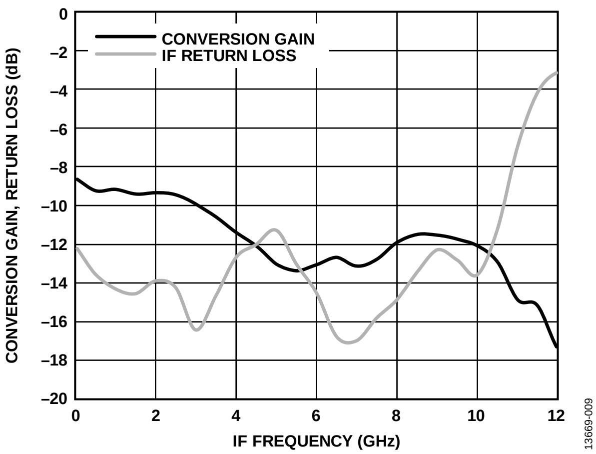


Figure 9. Conversion Gain and Return Loss vs. IF Frequency, LO Drive = 13 dBm

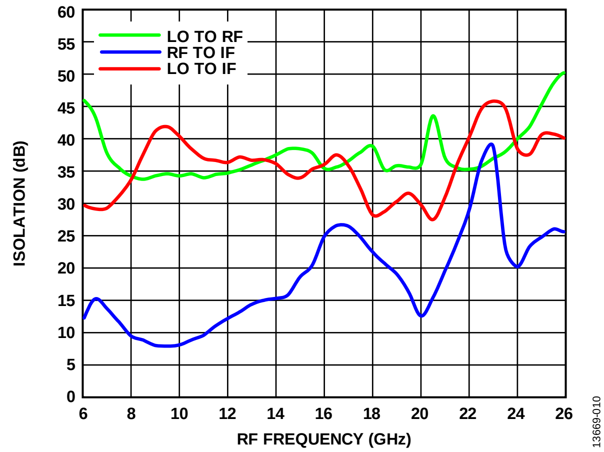


Figure 10. Isolation vs. RF Frequency

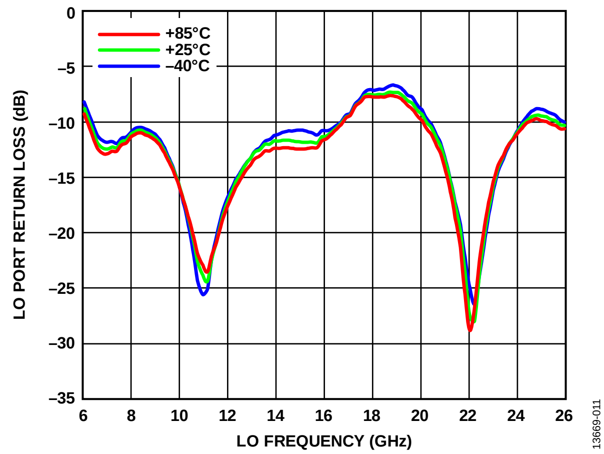


Figure 11. LO Port Return Loss vs. LO Frequency, LO Drive = 13 dBm

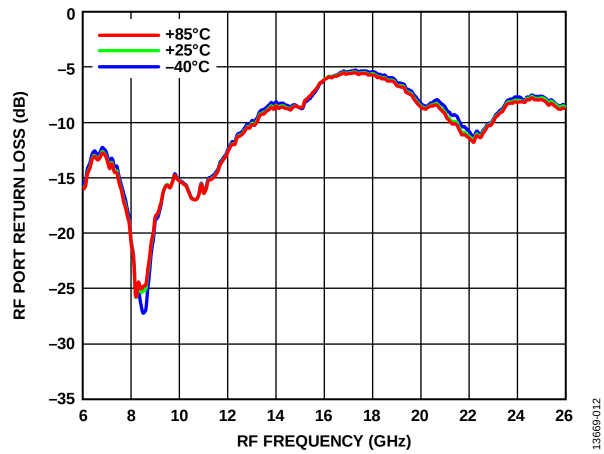


Figure 12. RF Port Return Loss vs. RF Frequency, LO Frequency = 16 GHz, LO Drive = 13 dBm

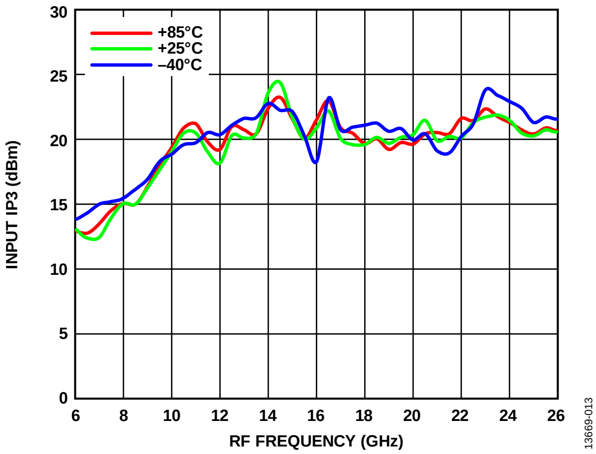


Figure 13. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

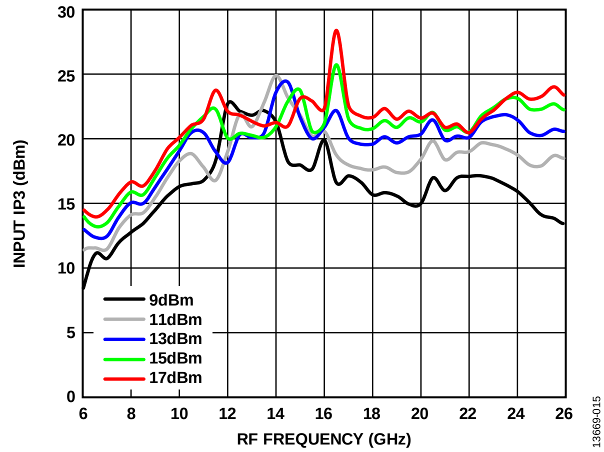
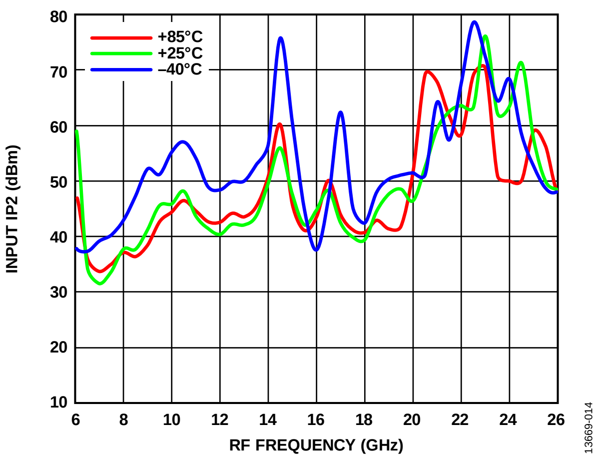


Figure 15. Input IP3 vs. RF Frequency at Various LO Drives



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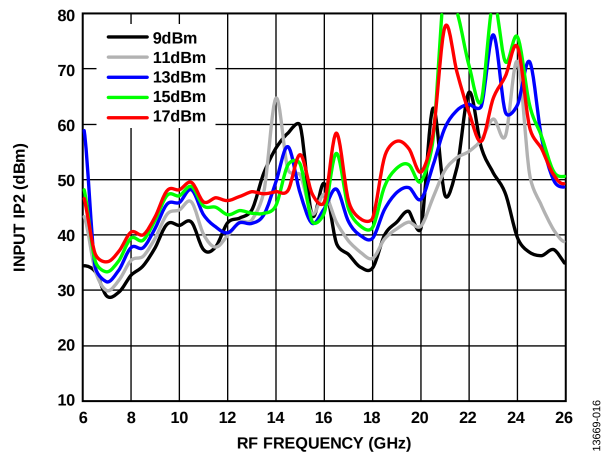

Figure 16. Input IP2 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, UPPER SIDEBAND, IF = 1000 MHz

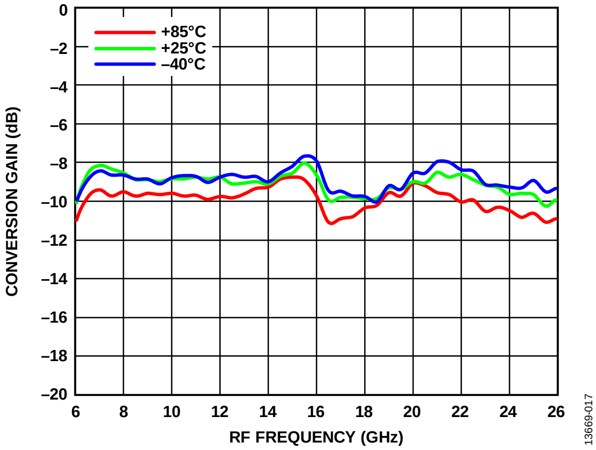

Figure 17. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

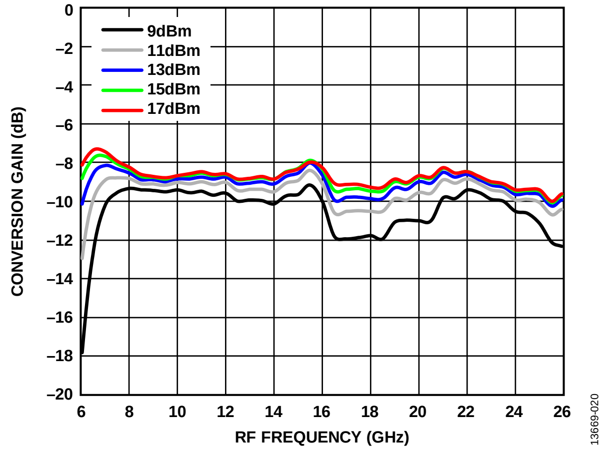

Figure 20. Conversion Gain vs. RF Frequency at Various LO Drives

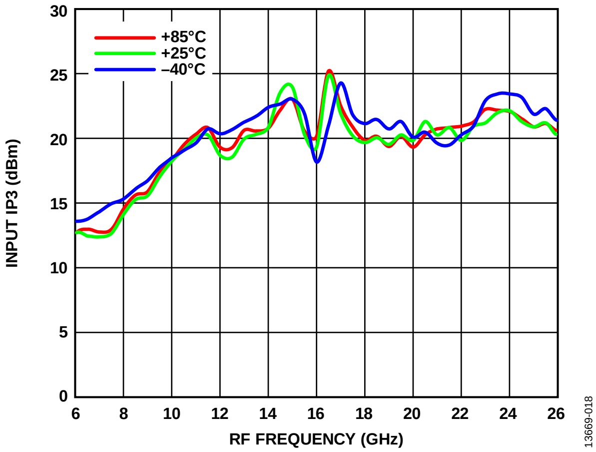

Figure 18. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

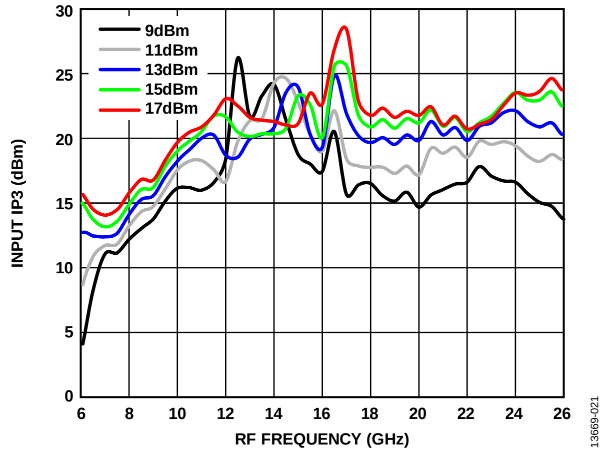

Figure 21. Input IP3 vs. RF Frequency at Various LO Drives

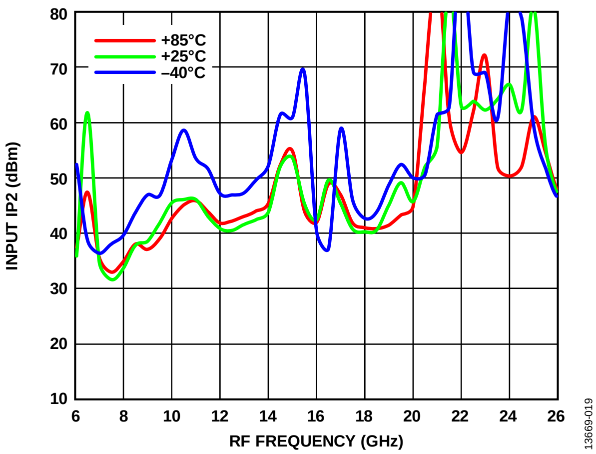

Figure 19. Input IP2 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

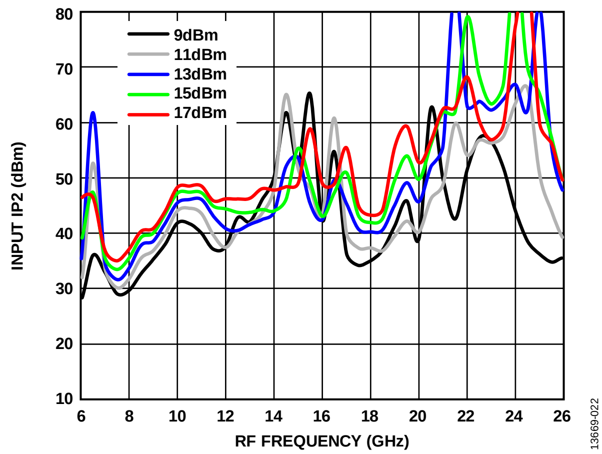

Figure 22. Input IP2 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, UPPER SIDEBAND, IF = 3000 MHz

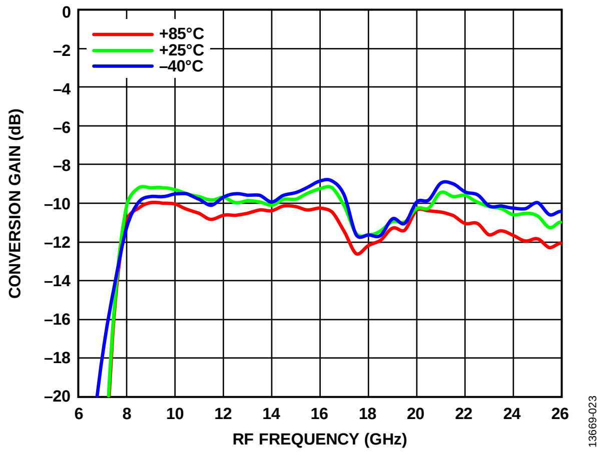

Figure 23. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

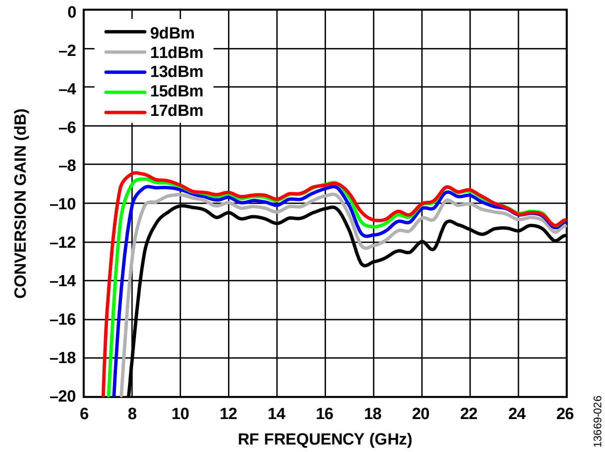

Figure 26. Conversion Gain vs. RF Frequency at Various LO Drives

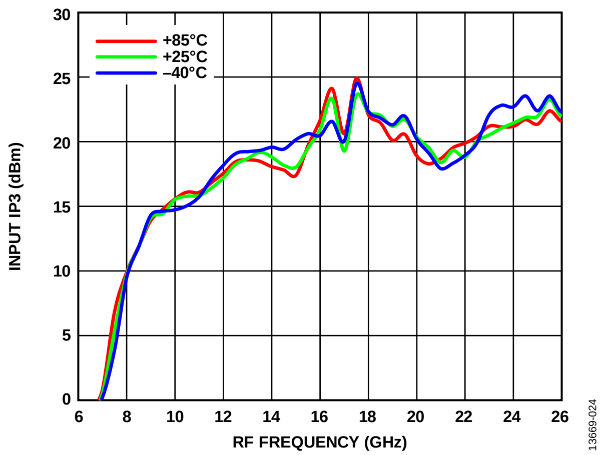

Figure 24. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

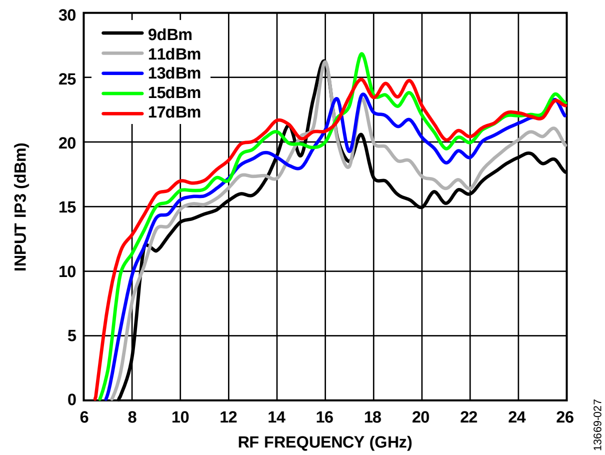

Figure 27. Input IP3 vs. RF Frequency at Various LO Drives

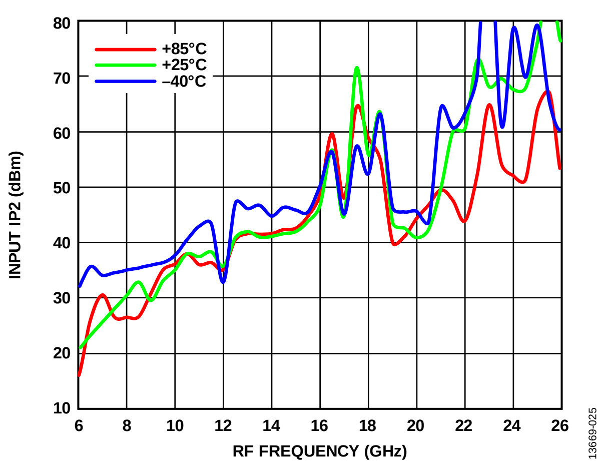

Figure 25. Input IP2 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

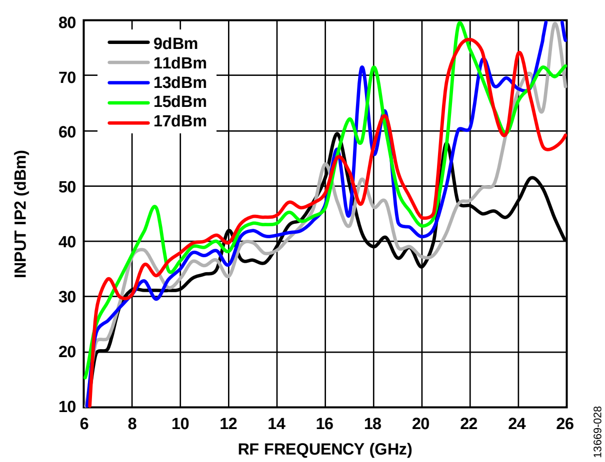

Figure 28. Input IP2 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, UPPER SIDEBAND, IF = 7000 MHz

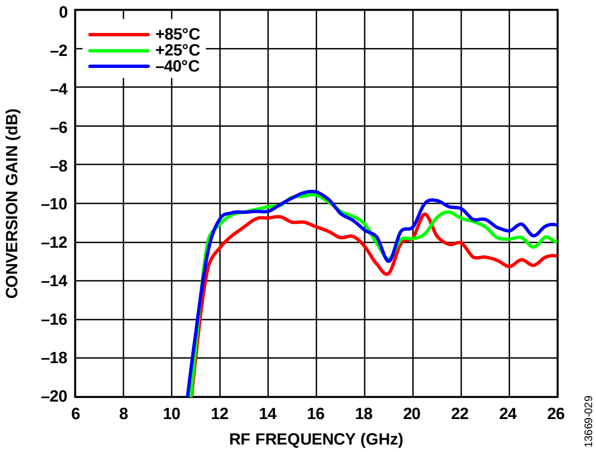

Figure 29. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

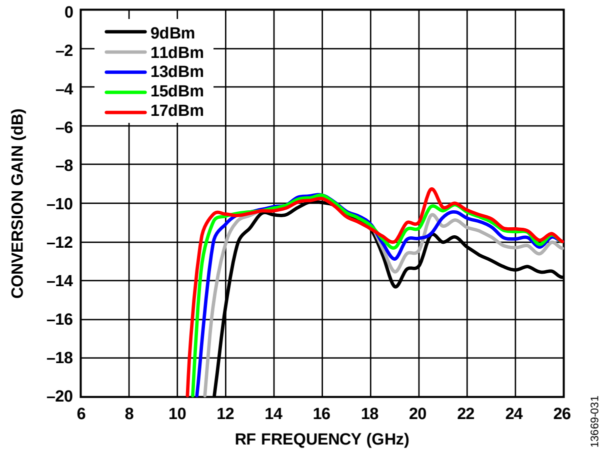

Figure 31. Conversion Gain vs. RF Frequency at Various LO Drives

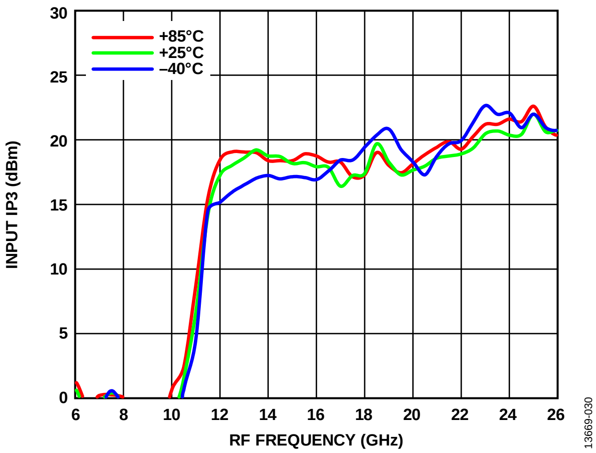

Figure 30. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

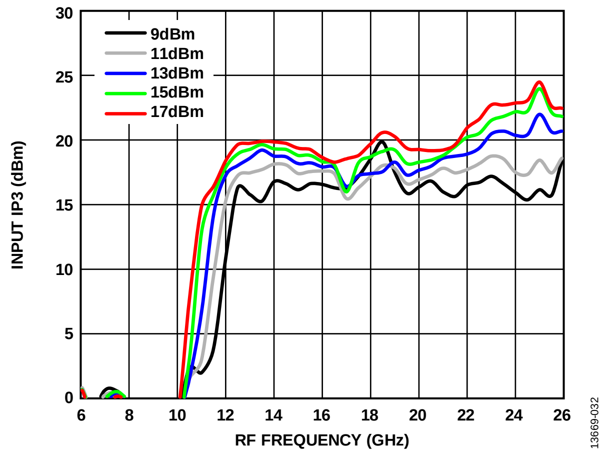

Figure 32. Input IP3 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, LOWER SIDEBAND, IF = 500 MHZ

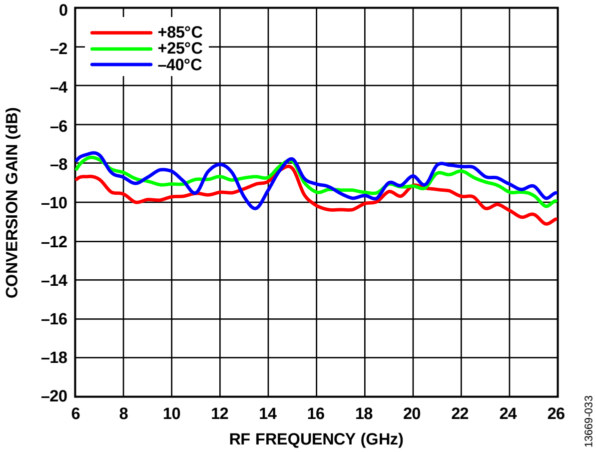

Figure 33. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

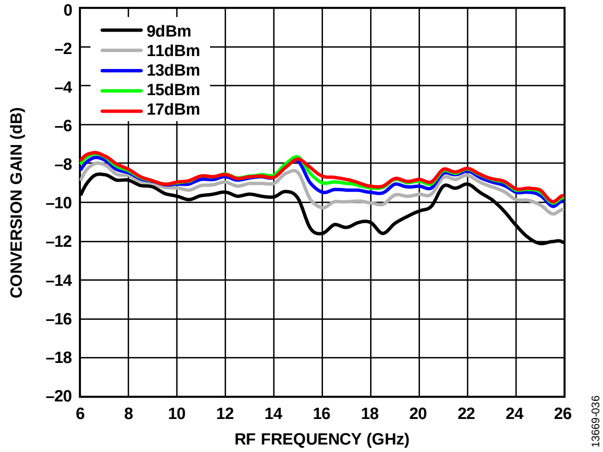

Figure 36. Conversion Gain vs. RF Frequency at Various LO Drives

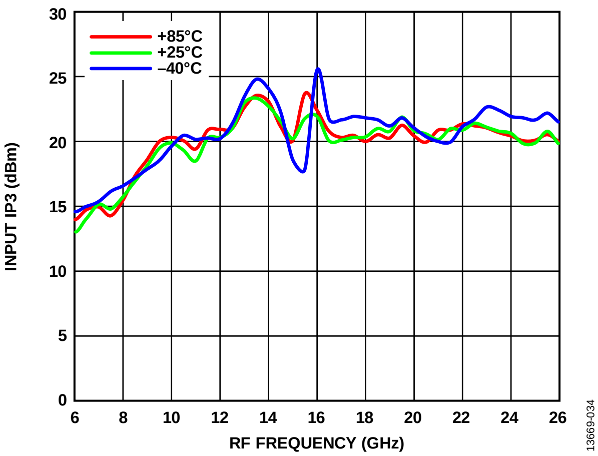

Figure 34. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

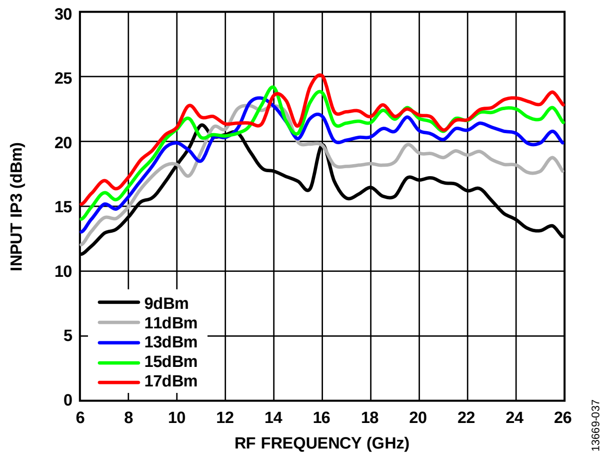

Figure 37. Input IP3 vs. RF Frequency at Various LO Drives

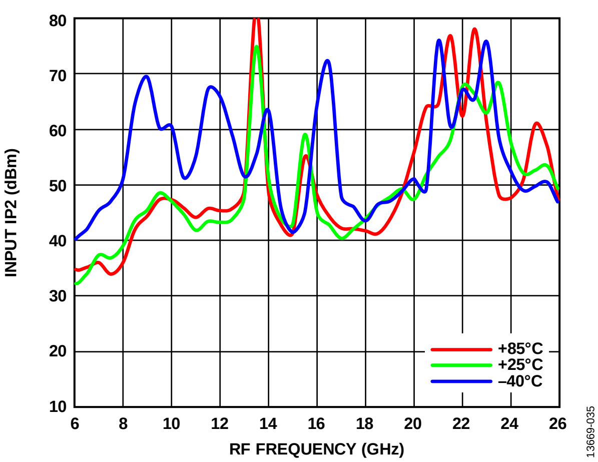

Figure 35. Input IP2 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

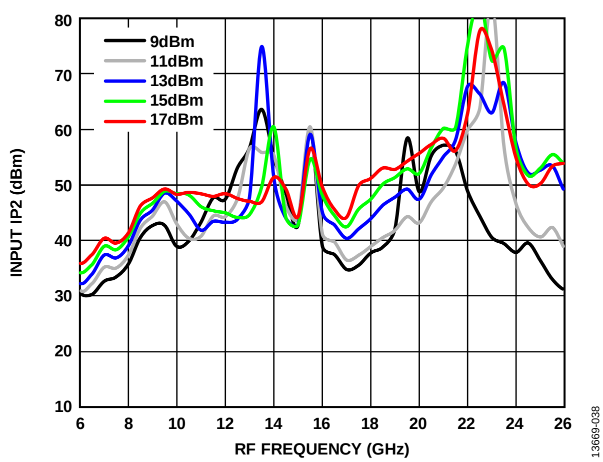

Figure 38. Input IP2 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, LOWER SIDEBAND, IF = 1000 MHz

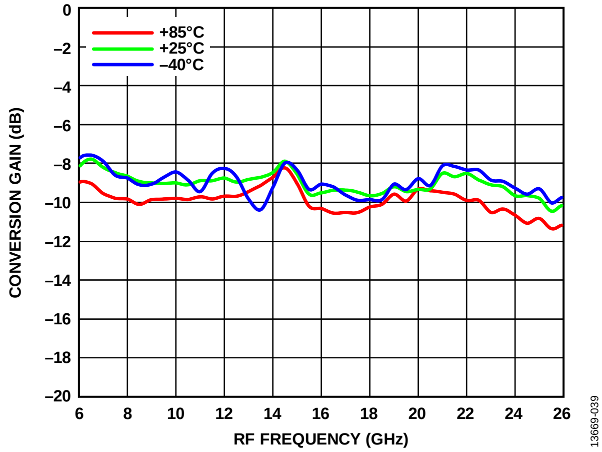

Figure 39. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

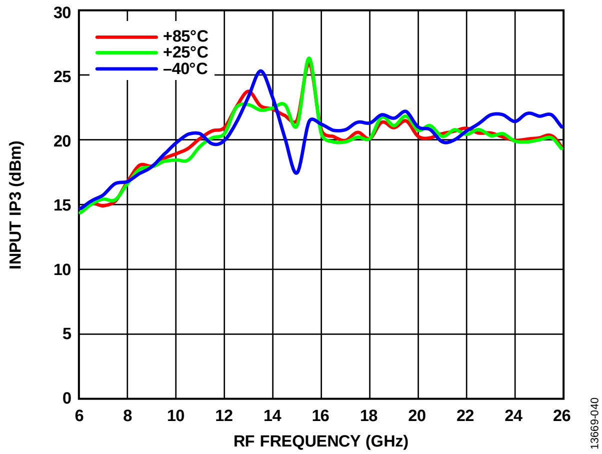

Figure 40. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

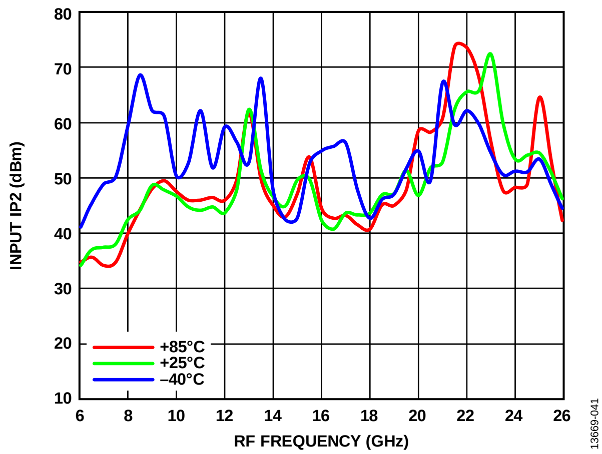

Figure 41. Input IP2 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

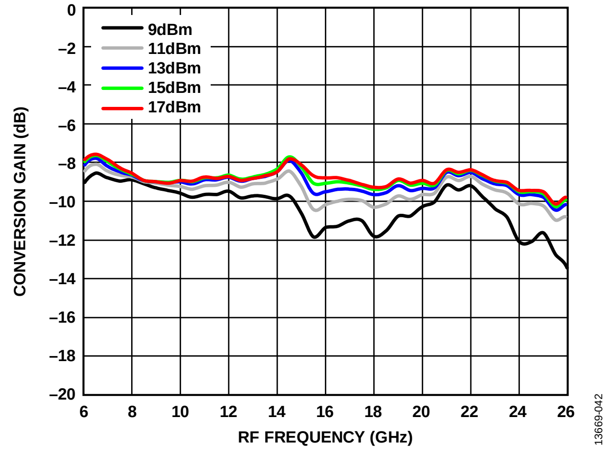

Figure 42. Conversion Gain vs. RF Frequency at Various LO Drives

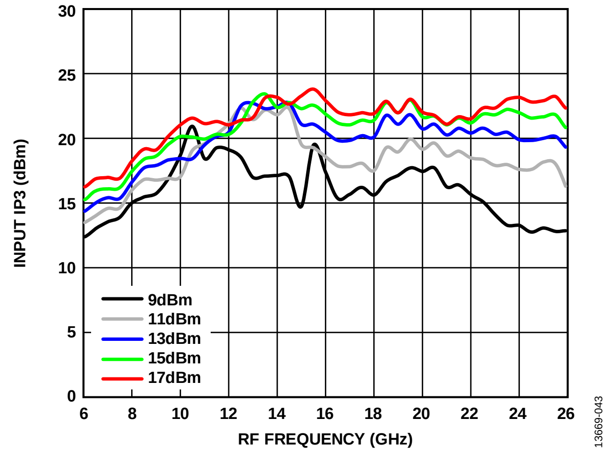

Figure 43. Input IP3 vs. RF Frequency at Various LO Drives

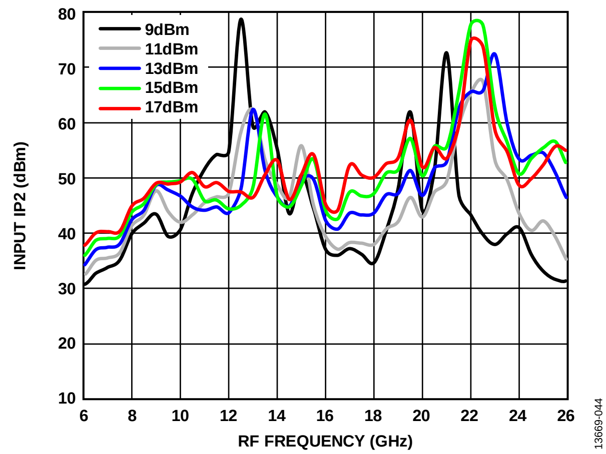

Figure 44. Input IP2 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, LOWER SIDEBAND, IF = 3000 MHz

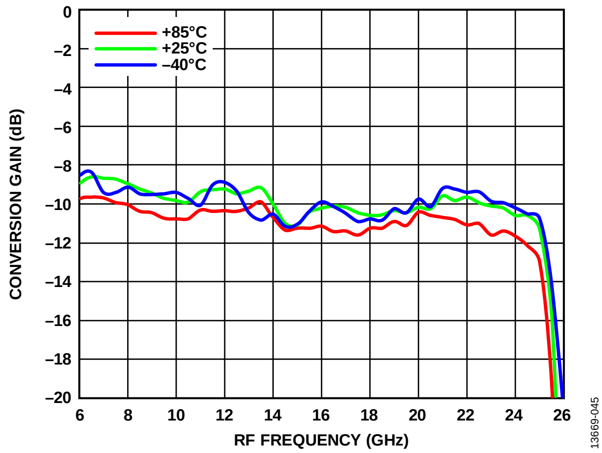

Figure 45. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

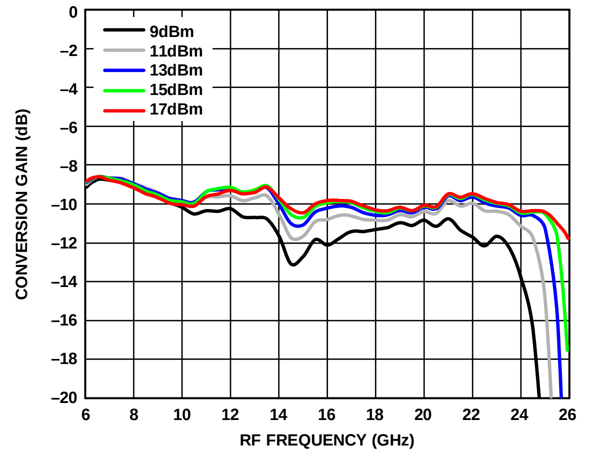

Figure 48. Conversion Gain vs. RF Frequency at Various LO Drives

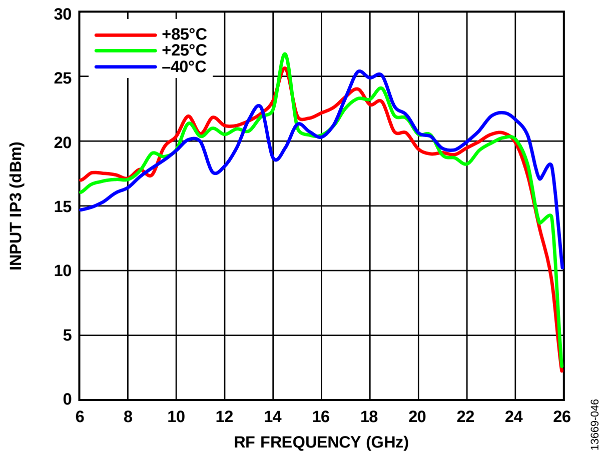

Figure 46. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

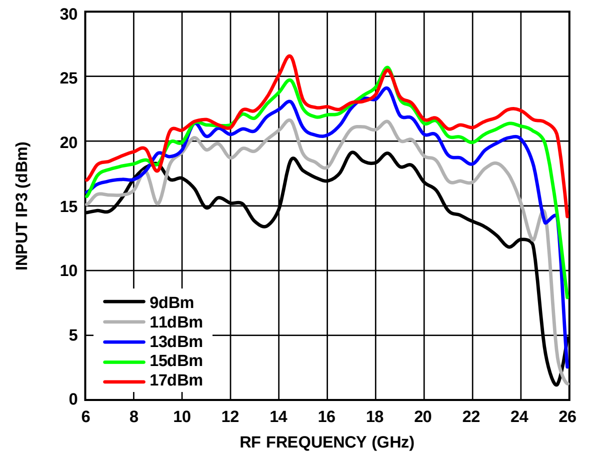

Figure 49. Input IP3 vs. RF Frequency at Various LO Drives

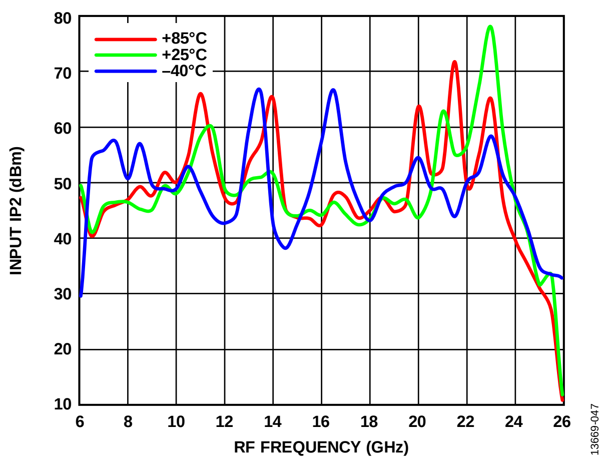

Figure 47. Input IP2 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

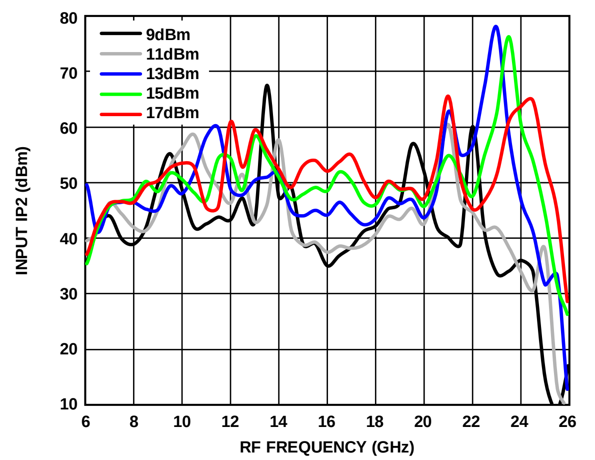

Figure 50. Input IP2 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, LOWER SIDEBAND, IF = 7000 MHz

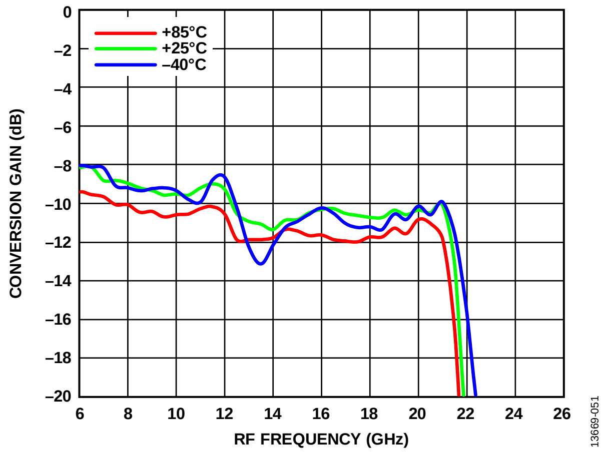

Figure 51. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

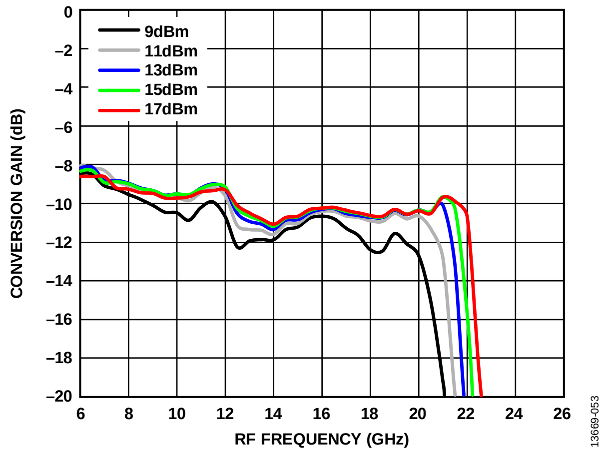

Figure 53. Conversion Gain vs. RF Frequency at Various LO Drives

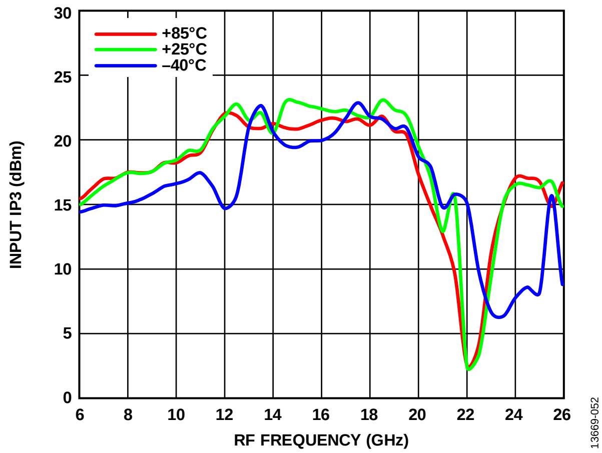

Figure 52. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm

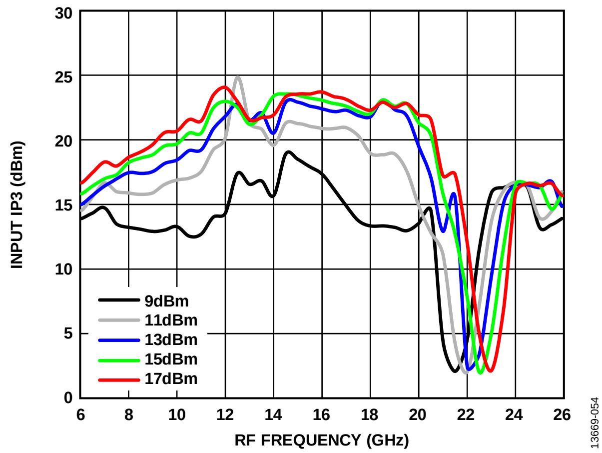

Figure 54. Input IP3 vs. RF Frequency at Various LO Drives

DOWNCONVERTER, P1dB PERFORMANCE

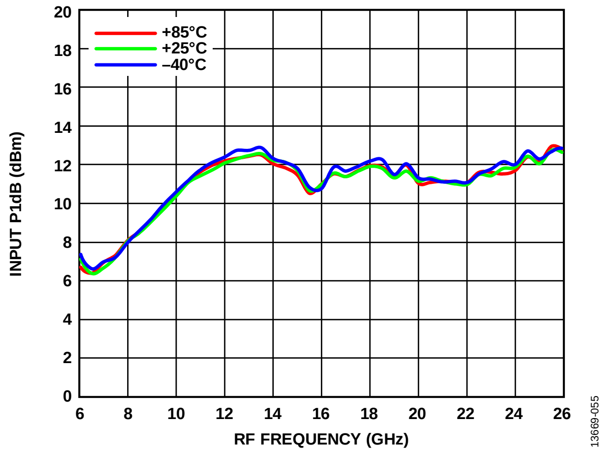

Figure 55. Input P1dB vs. RF Frequency at Various Temperatures, IF = 500 MHz, LO Drive = 13 dBm, Upper Sideband

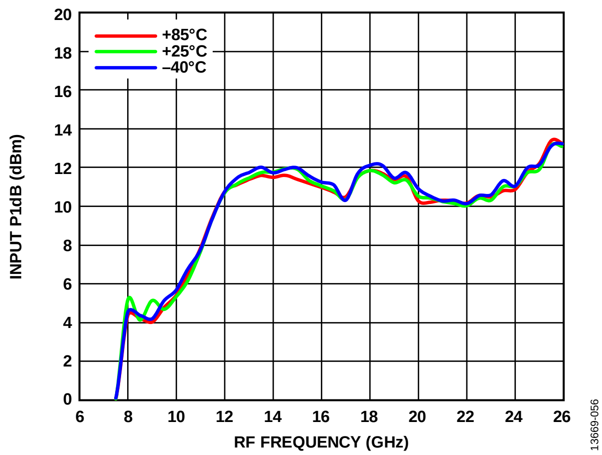

Figure 56. Input P1dB vs. RF Frequency at Various Temperatures, IF = 3000 MHz, LO Drive = 13 dBm, Upper Sideband

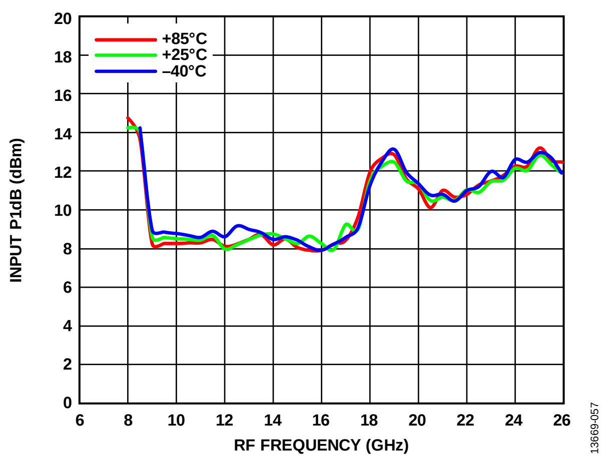

Figure 57. Input P1dB vs. RF Frequency at Various Temperatures, IF = 7000 MHz, LO Drive = 13 dBm, Upper Sideband

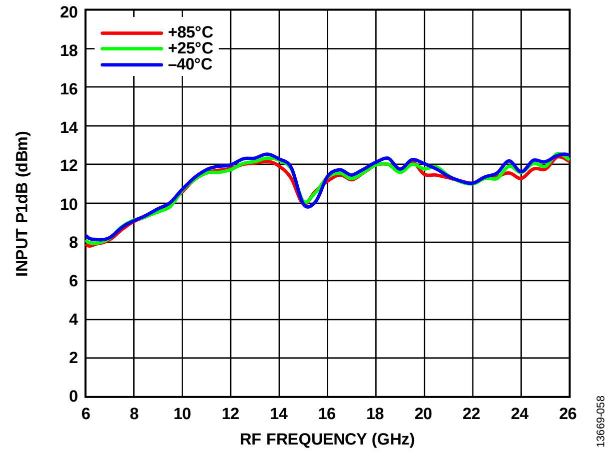

Figure 58. Input P1dB vs. RF Frequency at Various Temperatures, IF = 500 MHz, LO Drive = 13 dBm, Lower Sideband

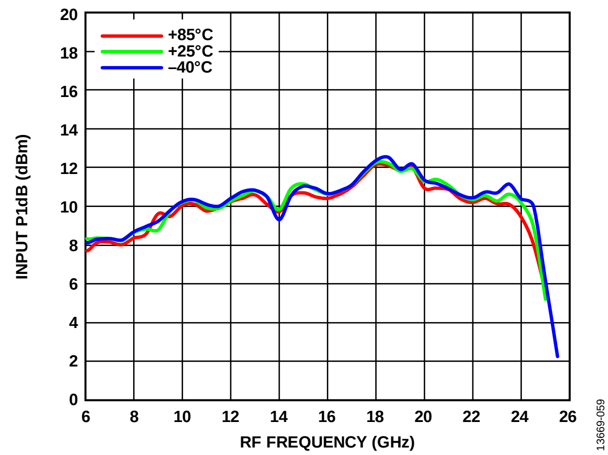

Figure 59. Input P1dB vs. RF Frequency at Various Temperatures, IF = 3000 MHz, LO Drive = 13 dBm, Lower Sideband

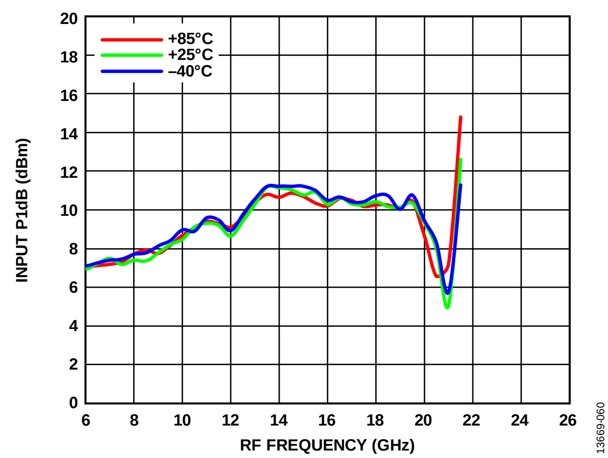

Figure 60. Input P1dB vs. RF Frequency at Various Temperatures, IF = 7000 MHz, LO Drive = 13 dBm, Lower Sideband

UPCONVERTER, UPPER SIDEBAND

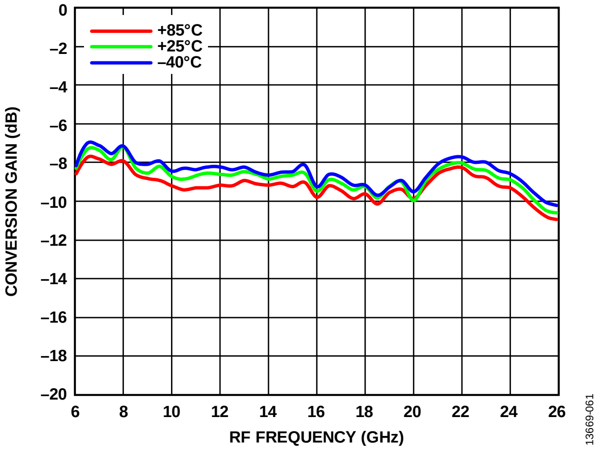

Figure 61. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 500 MHz

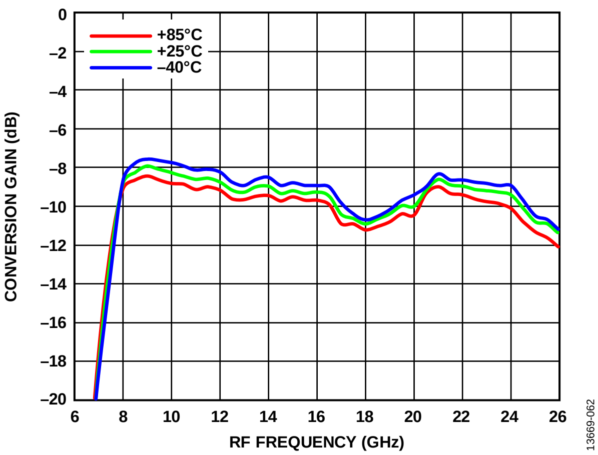

Figure 62. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 3000 MHz

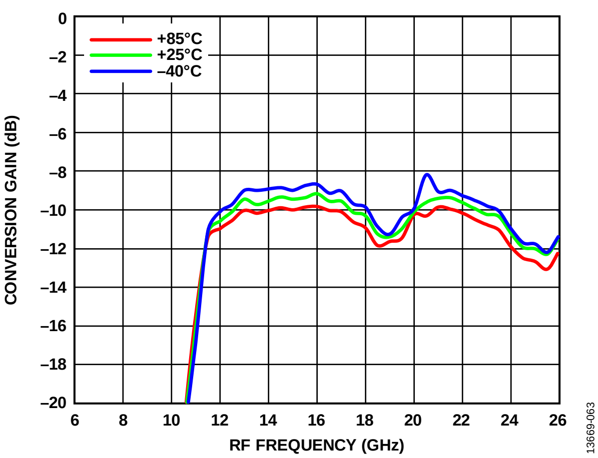

Figure 63. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 7000 MHz

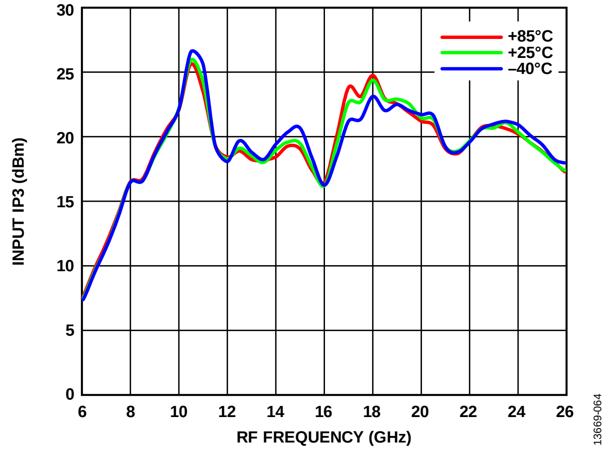

Figure 64. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 500 MHz

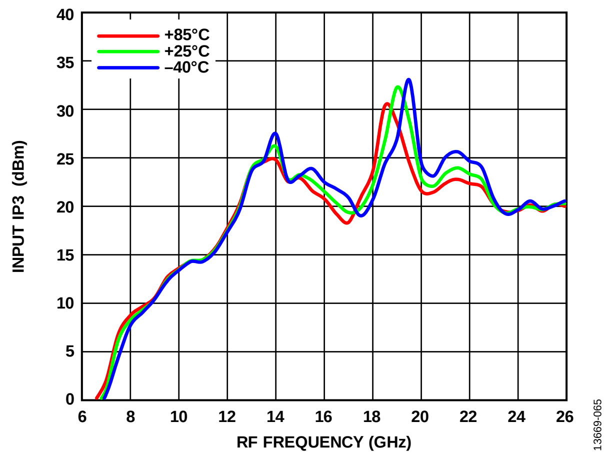

Figure 65. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 3000 MHz

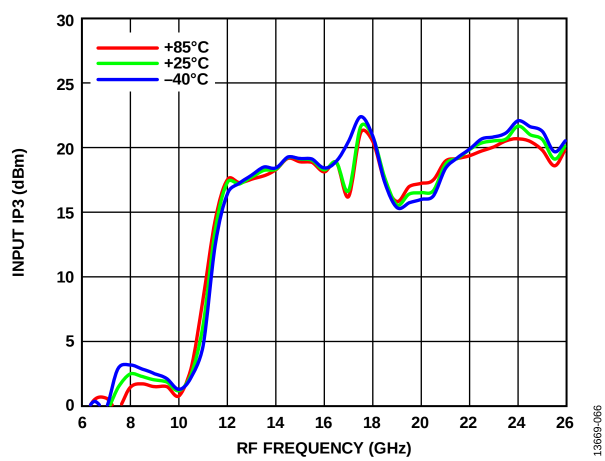

Figure 66. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 7000 MHz

UPCONVERTER, LOWER SIDEBAND

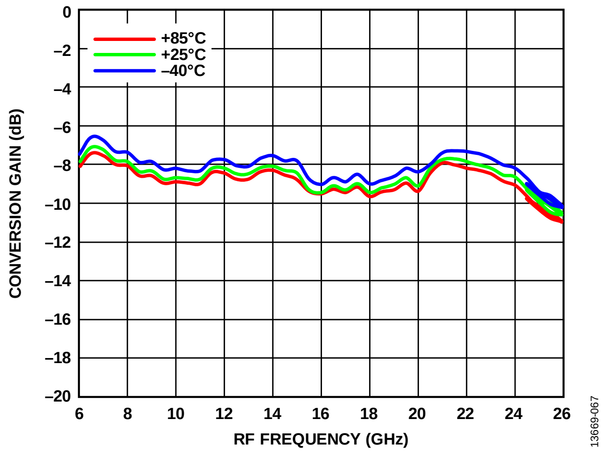

Figure 67. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 500 MHz

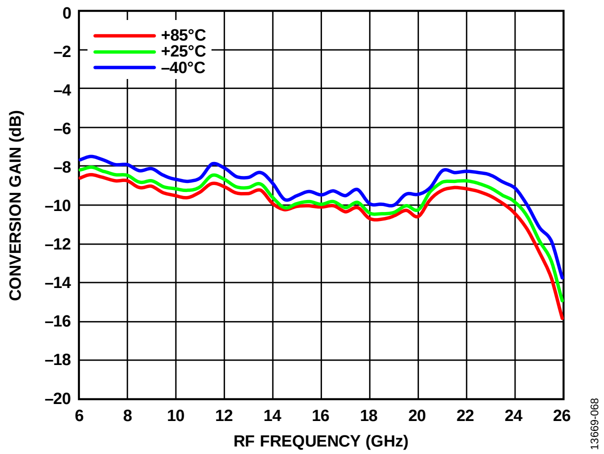

Figure 68. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 3000 MHz

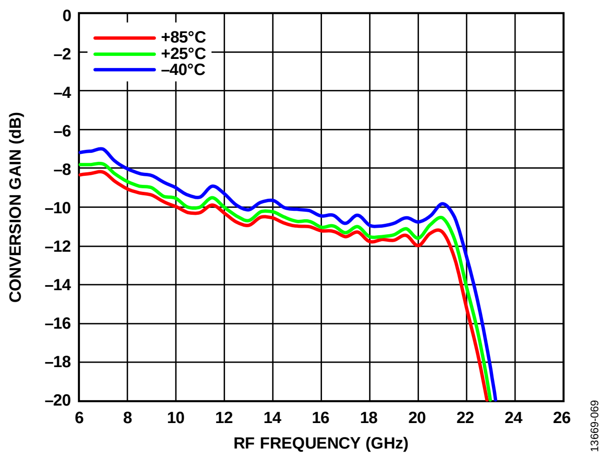

Figure 69. Conversion Gain vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 7000 MHz

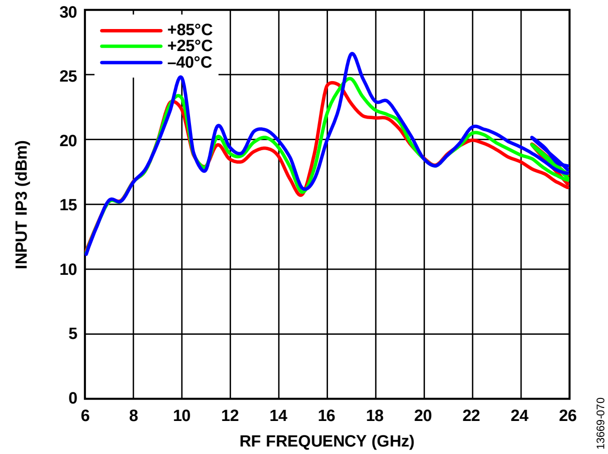

Figure 70. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 500 MHz

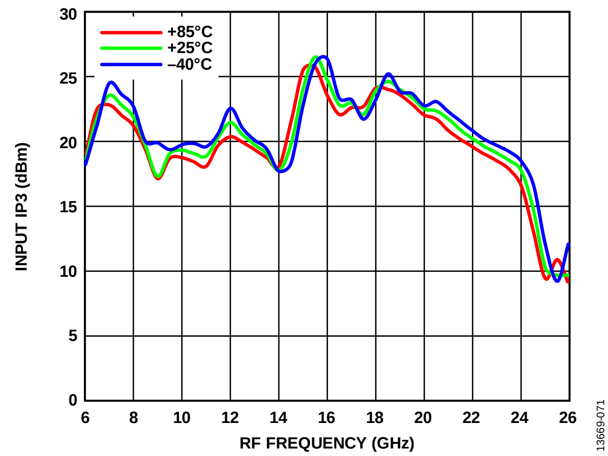

Figure 71. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 3000 MHz

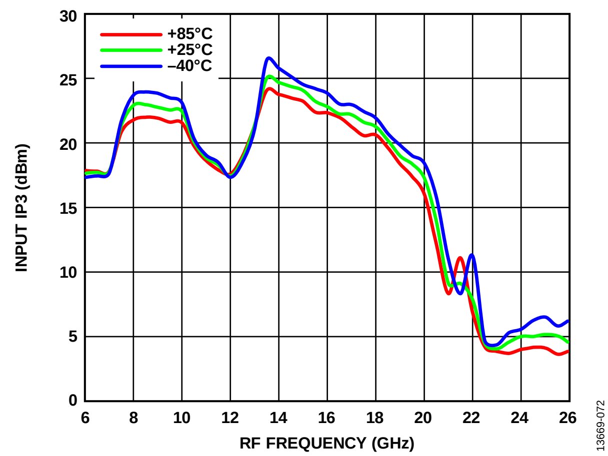

Figure 72. Input IP3 vs. RF Frequency at Various Temperatures, LO Drive = 13 dBm, IF = 7000 MHz

NOISE FIGURE PERFORMANCE

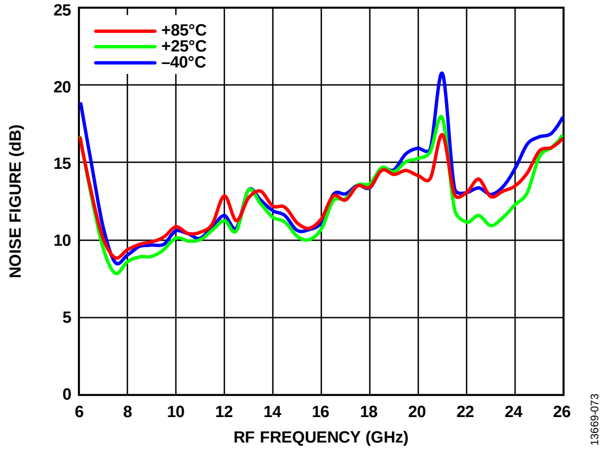

Figure 73. Noise Figure vs. RF Frequency at Various Temperatures, Upper Sideband, IF = 500 MHz, LO Drive = 13 dBm (with LO Amplifier in Line with Lab Bench LO Source)

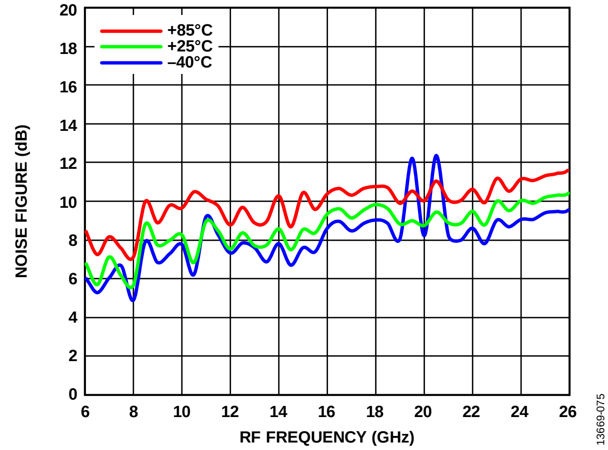

Figure 75. Noise Figure vs. RF Frequency at Various Temperatures, Upper Sideband, IF = 500 MHz, LO Drive = 13 dBm (Without LO Amplifier in Line with Lab Bench LO Source)

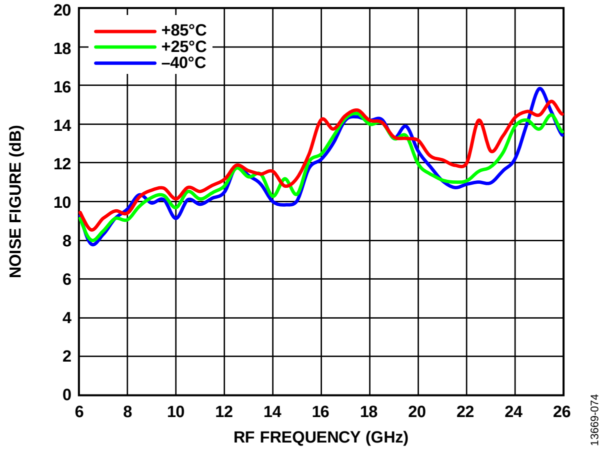

Figure 74. Noise Figure vs. RF Frequency at Various Temperatures, Lower Sideband, IF = 500 MHz, LO Drive = 13 dBm (with LO Amplifier in Line with Lab Bench LO Source)

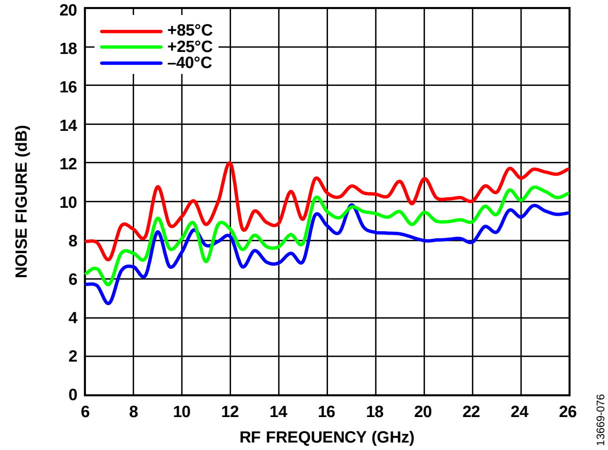

Figure 76. Noise Figure vs. RF Frequency at Various Temperatures, Lower Sideband, IF = 500 MHz, LO Drive = 13 dBm (Without LO Amplifier in Line with Lab Bench LO Source)

SPURIOUS PERFORMANCE

Mixer spurious products are measured in dBc from the IF output power level. Spurious values are (M × RF) − (N × LO). N/A means not applicable.

M × N Spurious Outputs, IF = 500 MHz

The RF frequency = 9 GHz and RF input power = −10 dBm. The LO frequency = 8.5 GHz and the LO input power = 13 dBm.

		N × LO					
		0	1	2	3	4	5
M × RF	0	N/A	+14	+33.9	+42.7	+74.4	+50.1
	1	−0.7	0	+18.4	+47.7	+46.1	+71.3
	2	+63.8	+58	+58.3	+64.4	+67.3	+86
	3	+73.1	+78.8	+53.1	+56.1	+62.6	+82.3
	4	+80.3	+90	+95.1	+95.2	+94.6	+97.3
	5	+78	+84.4	+88.7	+91.9	+87.5	+93.5

The RF frequency = 16 GHz and RF input power = −10 dBm. The LO frequency = 15.5 GHz and the LO input power = 13 dBm.

		N × LO					
		0	1	2	3	4	5
M × RF	0	N/A	10.5	47.3	44.1	N/A	N/A
	1	17.8	0	38.8	56.4	65.2	N/A
	2	85.1	63.9	51.6	66.3	83.3	629.7
	3	76.6	82.7	89.5	58.3	85.4	87.2
	4	N/A	74	89.9	91.3	97.4	92
	5	N/A	N/A	76.2	91.3	89.1	100.5

The RF frequency = 23 GHz and RF input power = −10 dBm. The LO frequency = 22.5 GHz and the LO input power = 13 dBm.

		N × LO					
		0	1	2	3	4	5
M × RF	0	N/A	11.2	38.7	N/A	N/A	N/A
	1	10.4	0	39.9	55.6	N/A	N/A
	2	78.1	69.7	58.8	73.1	76.3	N/A
	3	N/A	76.6	88.9	60.8	87.6	77
	4	N/A	N/A	78.5	91.6	91.8	87.3
	5	N/A	N/A	N/A	79	91.7	97.5

M × N Spurious Outputs, IF = 1000 MHz

The RF frequency = 9 GHz and RF input power = −10 dBm. The LO frequency = 8 GHz and the LO input power = 13 dBm.

		N × LO					
		0	1	2	3	4	5
M × RF	0	N/A	+11.9	+26.4	+62.6	+72.3	+49.1
	1	−0.4	0	+17.6	+61.1	+59	+68.2
	2	+63.4	+59.5	+59	+62.5	+90.4	+84.8
	3	+73.9	+77.1	+55.2	+53.7	+68.1	+77
	4	+81.6	+88.4	+91.2	+84.4	+98.2	+91.5
	5	+76.5	+85	+88.2	+89.8	+99.1	+98.1

The RF frequency = 16 GHz and RF input power = −10 dBm. The LO frequency = 15 GHz and the LO input power = 13 dBm.

		N × LO					
		0	1	2	3	4	5
M × RF	0	N/A	7.7	45.4	N/A	N/A	N/A
	1	17.7	0	35.3	63.7	N/A	N/A
	2	83.8	61.4	51.5	71	81.1	N/A
	3	75.6	88.5	74.9	58.7	79.1	76.1
	4	N/A	75	90	71.2	100.4	89.9
	5	N/A	N/A	75.7	91.1	95.4	99.2

The RF frequency = 23 GHz and RF input power = −10 dBm. The LO frequency = 22 GHz and the LO input power = 13 dBm.

		N × LO					
		0	1	2	3	4	5
M × RF	0	N/A	13.2	35.1	N/A	N/A	N/A
	1	10.4	0	41	57.6	N/A	N/A
	2	77.1	73.9	59.1	73.1	73	N/A
	3	N/A	77.3	91.8	60.5	89.3	N/A
	4	N/A	N/A	78.2	92.4	93.6	91.3
	5	N/A	N/A	N/A	77.3	93	100.1

THEORY OF OPERATION

The HMC773ALC3B is a general-purpose, double balanced mixer that can be used as an upconverter or a downconverter from 6 GHz to 26 GHZ.

When used a downconverter, the HMC773ALC3B downconverts radio frequencies (RF) between 6 GHz and 26 GHz to intermediate frequencies (IF) between dc and 8 GHz.

When used as an upconverter, the mixer upconverts intermediate frequencies between dc and 8 GHz to radio frequencies between 6 GHz and 26 GHz.

The mixer performs well with LO drives of 13 dBm or above, and it provides excellent LO to RF and LO to IF suppression due to optimized balun structures. The ceramic LCC package eliminates the need for wire bonding and is compatible with high volume, surface-mount manufacturing techniques.

APPLICATIONS INFORMATION

TYPICAL APPLICATION CIRCUIT

Figure 77 shows the typical application circuit for the HMC773ALC3B. The HMC773ALC3B is a passive device and does not require any external components. The LO and RF pins are internally ac-coupled. When IF operation is not required until dc, it is recommended to use an ac-coupled capacitor at the IF port. When IF operation to dc is required, do not exceed the IF source and sink current rating specified in the Absolute Maximum Ratings section.

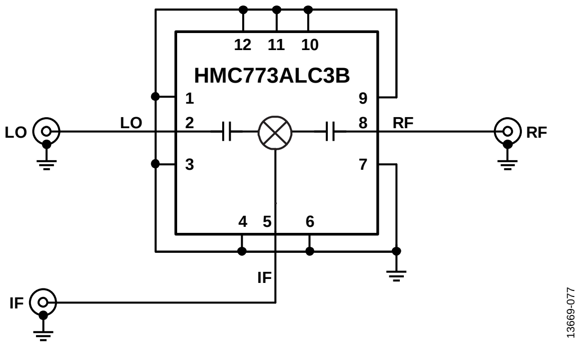

Figure 77. Typical Application Circuit

EVALUATION PCB INFORMATION

RF circuit design techniques must be implemented for the evaluation board PCB shown in Figure 78. Signal lines must have 50 Ω impedance, and the package ground leads and exposed pad must be connected directly to the ground plane, similar to that shown in Figure 78. Use a sufficient number of via holes to connect the top and bottom ground planes. The evaluation circuit board shown in Figure 78 is available from Analog Devices, Inc., upon request.

Table 6. Bill of Materials for Evaluation PCB EV1HMC773ALC3B

Item	Description
J1, J2	SRI SMA connector.
J3	Johnson SMA connector.
U1	HMC773ALC3B mixer.
PCB[1]	125040 evaluation PCB. Circuit board material: Rogers 4350.

[1] 125040 is the bare PCB. Reference EV1HMC773ALC3B when ordering the evaluation PCB assembly.

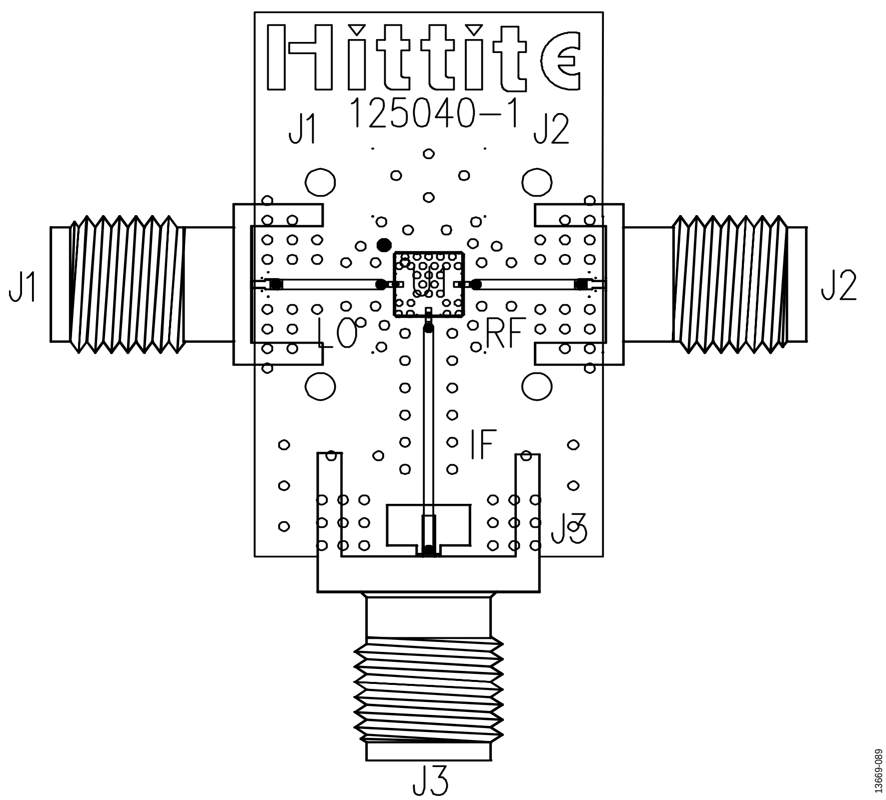

Figure 78. Evaluation PCB

OUTLINE DIMENSIONS

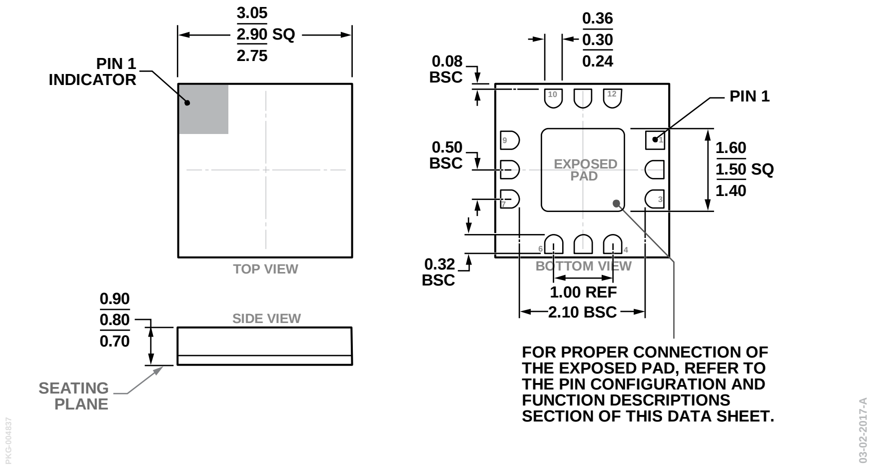

Figure 79. 12-Terminal Ceramic Leadless Chip Carrier [LCC]
(E-12-4)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	MSL Rating[2]	Description[3]	Package Option
HMC773ALC3B	−40°C to +85°C	MSL3	12-Terminal Ceramic Leadless Chip Carrier [LCC]	E-12-4
HMC773ALC3BTR	−40°C to +85°C	MSL3	12-Terminal Ceramic Leadless Chip Carrier [LCC]	E-12-4
HMC773ALC3BTR-R5	−40°C to +85°C	MSL3	12-Terminal Ceramic Leadless Chip Carrier [LCC]	E-12-4
EV1HMC773ALC3B			Evaluation PCB Assembly	

[1] All models are RoHS-Compliant Parts.
[2] The maximum peak reflow temperature is 260°C (see the Absolute Maximum Ratings section).
[3] HMC773ALC3B, HMC773ALC3BTR, and HMC773ALC3BTR-R5 body package material is alumina ceramic and the lead finish is gold over nickel.